

**THIRD SEMESTER B.TECH (E & C) DEGREE END SEMESTER EXAMINATION
NOV/DEC 2015**

SUBJECT: ANALOG ELECTRONIC CIRCUITS (ECE - 201)

TIME: 3 HOURS

MAX. MARKS: 50

Instructions to candidates

- Answer **ANY FIVE** full questions.
- Missing data may be suitably assumed.

1A.	The circuit of Figure 1A is used to provide required phase shift in a oscillator. Show that $V_f/V_o = 1/(3+j(\omega RC - 1/\omega RC))$. Also show that the frequency of oscillation is $f = 1/2\pi RC$ and the gain required for sustained oscillation is 3.
1B.	Calculate current gain, input and output resistance for the circuit shown in Figure 1B. Assume $h_{ie} = 1.1k\Omega$, $h_{fe} = 50$, $h_{oe} = 25\mu S$ and $h_{re} = 2.5 \times 10^{-4}$.
1C.	i) Input characteristic of BJT can be used to determine ____ and ____ hybrid parameters ii) Out of fixed bias and self-bias circuits; we get stable operating point in case of ____
(5+3+2)	
2A.	Calculate Current gain, Voltage gain, input and output resistance for the circuit shown in Figure 2A. For the BJT, use $h_{ie} = 1k\Omega$, $h_{fe} = 50$, $h_{re} = h_{oe} = 0$.
2B.	In the hybrid- π model of BJT shown in Figure 2B, what does each component represent?
2C.	Given that. $V_{BE} = V + (R_b + R_e) \frac{\beta + 1}{\beta} I_{C0} - \frac{R_b + R_e (1 + \beta)}{\beta} I_C$ Obtain an expression for stability factor $S = \frac{\partial I_C}{\partial I_{C0}}$
(5+3+2)	
3A.	Determine the values of f_H , f_L and mid-band gain for the amplifier circuit shown in Figure 3A. Assume $h_{ie} = 1.1k\Omega$, $h_{fe} = 50$, $h_{re} = h_{oe} = 0$, $g_m = 1.4 \times 10^{-3} A/V$, $r_{b'e} = 1k\Omega$, $c_{b'e} = 4pF$, $c_{b'c} = 36pF$.
3B.	Show that the transformer coupling has double the conversion efficiency over direct coupling?
3C.	A transistor supplies 0.85W of power to a $4k\Omega$ load. The zero-signal dc collector current is 31mA, and the dc collector current with signal is 34mA. Determine the % of second harmonic distortion.
(5+3+2)	
4A.	Calculate voltage gain, input and output impedance for the FET amplifier shown in Figure 4A. Assume $g_m = 2 \times 10^{-3} A/V$ and $r_d = 40k\Omega$.
4B.	For an n-channel JFET obtain an expression for drain current I_D in terms of device parameters (a, w and L), electron mobility μ_n , doping concentration N_D , gate to source voltage V_{GS} , pinch-off voltage V_P and drain to source voltage V_{DS} .
4C.	In the circuit of Figure 4(C), i) we observe ____ and ____ configuration. ii) Q2 stage will have a current gain of less than one (T/F)
(5+3+2)	

5A.	In the circuit of Figure 5(A); BJT has $h_{fe}=50$, $h_{ie}=1.1k\Omega$, $h_{re}=h_{oe}=0$; $R_C=330\Omega$, $R=47K\Omega$ and $R_E=120\Omega$. Determine the input resistance seen by the source V_i . Assume capacitor to act as short circuit at the operating frequency
5B.	Define three types of sweep error and derive a relation between them
5C.	i) Negative feedback _____ bandwidth and reduces _____. ii) Current series feedback decreases _____, and increases _____, _____, and _____.
(5+3+2)	
6A.	Using necessary diagram and analysis of a sinusoidal oscillator using L and C; show that we need either two inductors and one capacitor or one capacitor and two inductors to construct a LC-oscillator.
6B.	Verify if the following statements are True or False for the block diagram shown in Figure 6B. i) The block diagram represents Voltage shunt feedback system ii) The type of feedback used here is useful in case of Current Amplifier iii) With feedback both the input and output resistance decreases.
6C.	Three identical cascaded stages have an overall upper 3-dB frequency of 20 kHz and lower 3-dB frequency of 20Hz. What are f_L and f_H of each stage? Assume non-interacting stages
(5+3+2)	

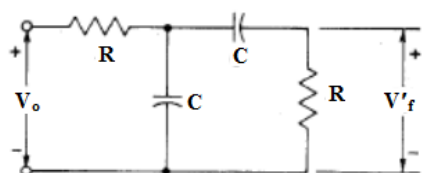


Figure 1A

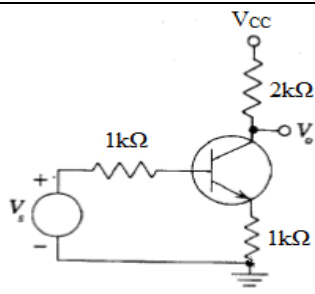


Figure 1B

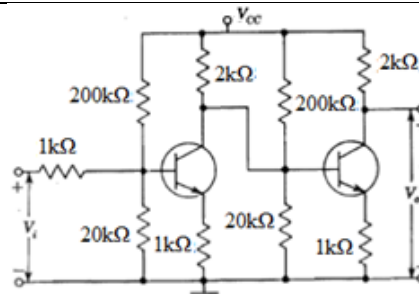


Figure 2A

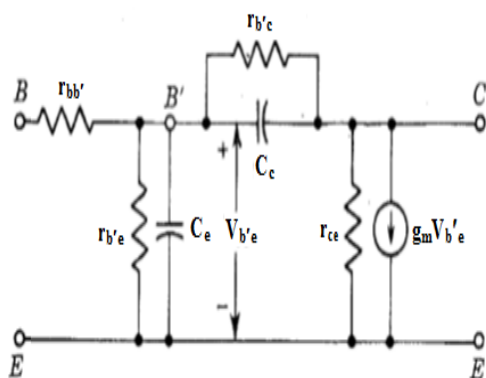


Figure 2B

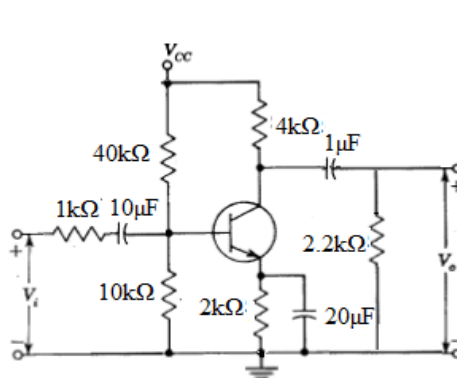


Figure 3A

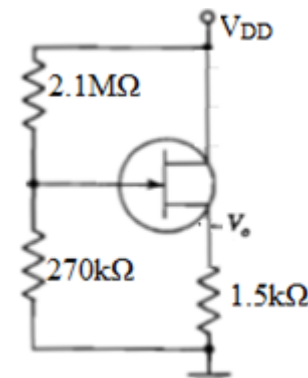


Figure 4A

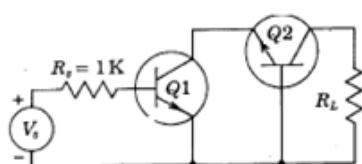


Figure 4C

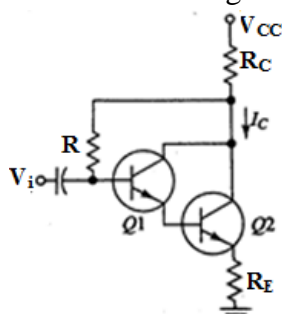


Figure 5A

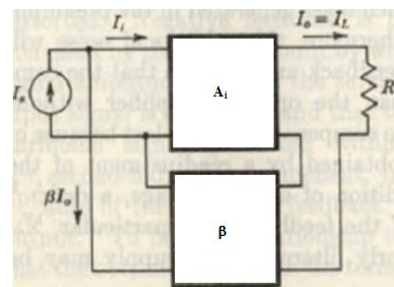


Figure 6B